## PATENT ABSTRACTS OF JAPAN

(11)Publication number:

05-241201

(43) Date of publication of application: 21.09.1993

(51)Int.Cl.

G02F 1/136 G02F 1/133 G02F 1/1345 G09F 9/30 G09G 3/36 H01L 27/12

H01L 29/784

(21)Application number : 04-080450

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(22)Date of filing:

02.03.1992

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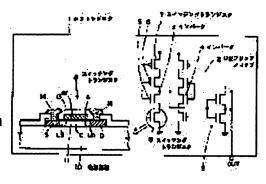
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## (54) VERTICAL DRIVING CIRCUIT

## (57)Abstract:

PURPOSE: To prevent the malfunction of the vertical driving circuit to be built into an active matrix type liquid crystal display device, etc.

constitution: The vertical driving circuit to be built into the active matrix type liquid crystal display device includes a shift register 1 and successively generates vertical driving pulses. At least a part of the plural transistors constituting the shift register 1, for example, a switching transistor 8, is made into an LDD structure, by which the voltage resistance of sources/drains is improved and leak currents are suppressed. This LDD structure has regions LS, LD which are adjacent to at least one region of the source region S and drain region D, are of the same conduction type as the conduction type of the source region S or drain region D and is low in impurity concn.



## **LEGAL STATUS**

[Date of request for examination]

23.02.1999

[Date of sending the examiner's decision of

13.03.2001

rejection]

[Kind of final disposal of application other than the examiner's decision of rejection or application converted registration]

[Date of final disposal for application]

[Patent number]

[Date of registration]

[Number of appeal against examiner's decision of rejection]

[Date of requesting appeal against examiner's decision of rejection]

[Date of extinction of right]